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<u>International Rectifier (Infineon Technologies Americas Corp.)</u>
<u>IR2122</u>

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International Rectifier

Preliminary Data Sheet No. PD60130-K

IR2122(S)

CURRENT SENSING SINGLE CHANNEL DRIVER

Features

- Floating channel designed for bootstrap operation Fully operational to +600V Tolerant to negative transient voltage dV/dt immune
- Gate drive supply range from 10 to 20V
- Undervoltage lockout
- 3.3V, 5V and 15V input logic compatible
- FAULT lead indicates shutdown has occured
- Output out of phase with input

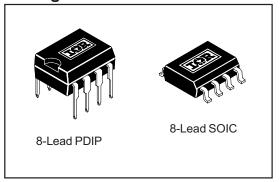
Description

The IR2122(S) is a high voltage, high speed power MOSFET and IGBT driver. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL outputs, down to 3.3V. The protection circuity detects over-current in the driven power transistor and terminates the gate drive voltage. An open drain FAULT signal is provided to indicate that an over-current shutdown has occurred. The output driver features a high pulse current buffer stage designed for minimum cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side or low side configuration which operates up to 600 volts.

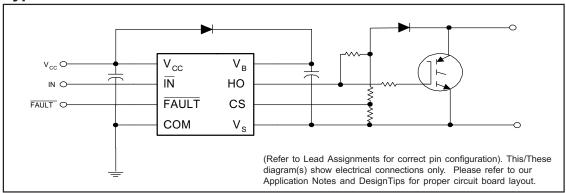
Product Summary

Voffset	600V max.
I _O +/-	110 mA / 110 mA
Vout	10 - 20V
Vcsth	500 mV
t _{on/off} (typ.)	250 & 200 ns

Packages



Typical Connection



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Absolute Maximum Ratings

Absolute Maximum Ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The Thermal Resistance and Power Dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition		Min.	Max.	Units
V _B	High Side Floating Supply Voltage		-0.3	625	
Vs	High Side Floating Offset Voltage		V _B - 25	V _B + 0.3	
V _{HO}	High Side Floating Output Voltage		V _S - 0.3	V _B + 0.3	
V _{CC}	Logic Supply Voltage		-0.3	25	V
V _{IN}	Logic Input Voltage		-0.3	V _{CC} + 0.3	
V _{FLT}	FAULT Output Voltage		-0.3	V _{CC} + 0.3	
Vcs	Current Sense Voltage		Vs - 0.3	V _B + 0.3	
dV _S /dt	Allowable Offset Supply Voltage Transient		_	50	V/ns
PD	Package Power Dissipation @ T _A ≤ +25°C	(8 Lead DIP)	_	1.0	W
		(8 Lead SOIC)	_	0.625	VV
R _{THJA}	Thermal Resistance, Junction to Ambient	(8 Lead DIP)	_	125	°C/W
		(8 Lead SOIC)	_	200	C/VV
TJ	Junction Temperature		_	150	
Ts	Storage Temperature		-55	150	°C
TL	Lead Temperature (Soldering, 10 seconds)		_	300	

Recommended Operating Conditions

The Input/Output logic timing diagram is shown in Figure 1. For proper operation the device should be used within the recommended conditions. The V_S offset rating is tested with all supplies biased at 15V differential.

Symbol	Definition	Min.	Max.	Units
V _B	High Side Floating Supply Voltage	V _S + 13	V _S + 20	
Vs	High Side Floating Offset Voltage	Note 1	600	
VHO	High Side Floating Output Voltage	Vs	V _B	
V _{CC}	Logic Supply Voltage	13	20	V
V _{IN}	Logic Input Voltage	0	V _{CC}	
V _{FLT}	FAULT Output Voltage	0	V _{CC}	
Vcs	Current Sense Signal Voltage	Vs	V _S + 5	
TA	Ambient Temperature	-40	150	C

Note 1: Logic operational for V_S of -5 to +600V. Logic state held for V_S of -5V to -V_{BS}. (Please refer to the Design Tip DT97-3 for more details).



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Dynamic Electrical Characteristics

 V_{BIAS} (V_{CC} , V_{BS}) = 15V, C_L = 1000 pF and T_A = 25°C unless otherwise specified. The dynamic electrical characteristics are measured using the test circuit shown in Figure 3.

Symbol	Definition	Min.	Тур.	Max.	Units	Test Conditions
t _{on}	Turn-On Propagation Delay	_	250	_		V _S = 0V
t _{off}	Turn-Off Propagation Delay	_	200	_		V _S = 600V
t _r	Turn-On Rise Time	_	250	_		C _L = 1000 pF
t _f	Turn-Off Fall Time	_	250	_	ns	C _L = 1000 pF
t _{bl}	Start-Up Blanking Time	500	900	_		
t _{cs}	CS Shutdown Propagation Delay	_	350	_		
t _{flt}	CS to FAULT Pull-Up Propagation Delay	_	450	_		

Static Electrical Characteristics

 V_{BIAS} (V_{CC} , V_{BS}) = 15V and T_A = 25°C unless otherwise specified. The V_{IN} , V_{TH} and I_{IN} parameters are referenced to COM. The V_O and I_O parameters are referenced to V_S .

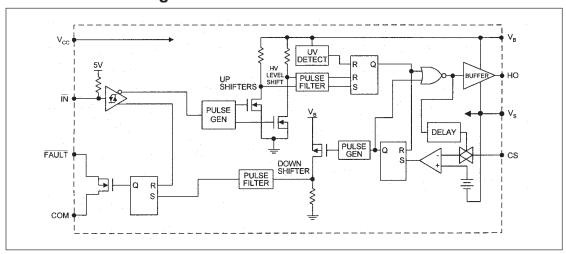
Symbol	Definition	Min.	Тур.	Max.	Units	Test Conditions
V _{IH}	Logic "0" Input Voltage (OUT = LO)	3.0	_	_	.,	V _{CC} = 10V to 20V
V _{IL}	Logic "1" Input Voltage (OUT = HI)	_	_	0.8	V	V _{CC} = 10V to 20V
V _{CSTH+}	CS Input Positive Going Threshold	350	500	650		V _{CC} = 10V to 20V
V _{OH}	High Level Output Voltage, V _{BIAS} - VO	_	_	100		IO = 0A
V _{OL}	Low Level Output Voltage, VO	_	_	100	mV	IO = 0A
I _{LK}	Offset Supply Leakage Current	_	_	50		$V_{B} = V_{S} = 600V$
I _{QBS}	Quiescent V _{BS} Supply Current	_	150	350		V _{IN} = 0V or 5V
I _{QCC}	Quiescent V _{CC} Supply Current	_	60	120		V _{IN} = 0V or 5V
I _{IN+}	Logic "1" Input Bias Current	_	7.0	15	μA	V _{IN} = 0V
I _{IN-}	Logic "0" Input Bias Current	_	_	1.0		V _{IN} = 5V
I _{CS+}	"High" CS Bias Current	_	_	1.0		V _{CS} = 3V
I _{CS-}	"High" CS Bias Current	_	_	1.0		V _{CS} = 0V
V _{BSUV+}	V _{BS} Supply Undervoltage Positive Going Threshold	10.0	11.4	13.0	.,	
V _{BSUV} -	V _{BS} Supply Undervoltage Negative Going Threshold	9.5	10.4	12.5	V	
I _{O+}	Output High Short Circuit Pulsed Current	110	130	_	mA	$V_O = 0V, V_{IN} = 0V$ $PW \le 10 \mu s$
I _{O-}	Output Low Short Circuit Pulsed Current	110	130	_	IIIA	$V_{O} = 15V, V_{IN} = 5V$ PW \le 10 \mus



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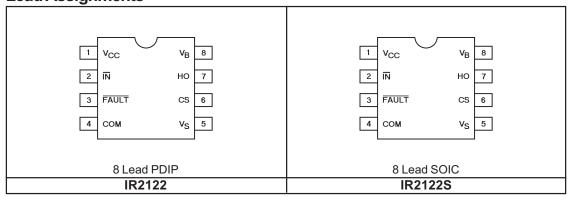
Functional Block Diagram



Lead Definitions

Lead		
Symbol	Description	
V _{CC}	Logic and gate drive supply	
V _{CC}	Logic input for gate driver output (HO), out of phase with HO	
FAULT	Indicates over-current shutdown has occurred, negative logic	
COM	Logic ground	
V_B	High side floating supply	
НО	High side gate drive output	
Vs	High side floating supply return	
CS	Current sense input to current sense comparator	

Lead Assignments



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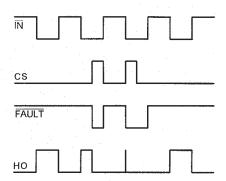


Figure 1. Input/Output Timing Diagram

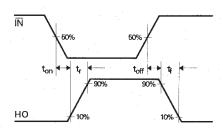


Figure 2. Switching Time Waveform Definition

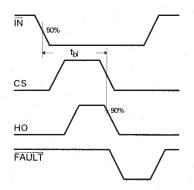


Figure 3. Start-up Blanking Time Waveform Definitions

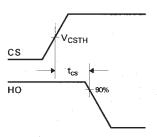


Figure 4. CS Shutdown Waveform Definitions

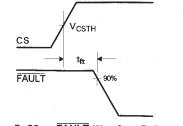
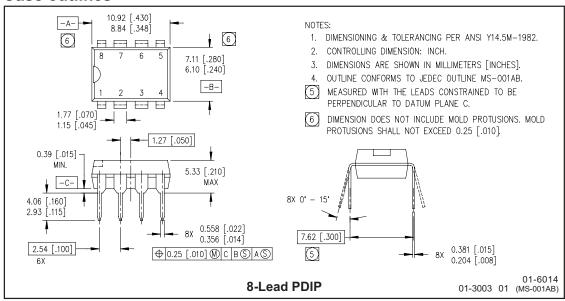


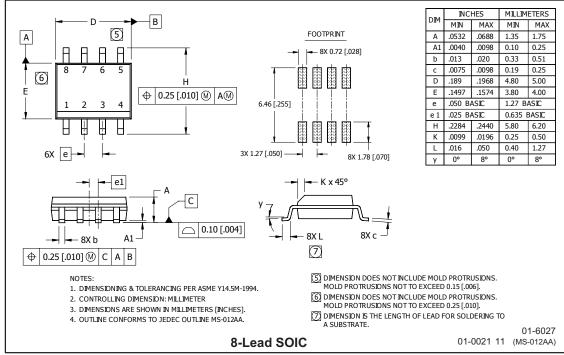
Figure 5. CS to FAULT Waveform Definitions

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Case outlines





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Data and specifications subject to change without notice. 2/2/2005